



■ General Description

The AME8890 is a fixed 1.2V of positive, linear regulator feature low quiescent current (30 μ A typ.) with low dropout voltage, making them ideal for battery applications. The space-saving SOT-23-5 package is attractive for "Pocket" and "Hand Held" applications.

This rugged device has both Thermal Shutdown, and Current Fold-back to prevent device failure under the "Worst" of operating conditions.

An additional feature is a "Power Good" detector, which pulls low when the output is out of regulation.

The AME8890 is stable with an output capacitor of 2.2 μ F or greater.

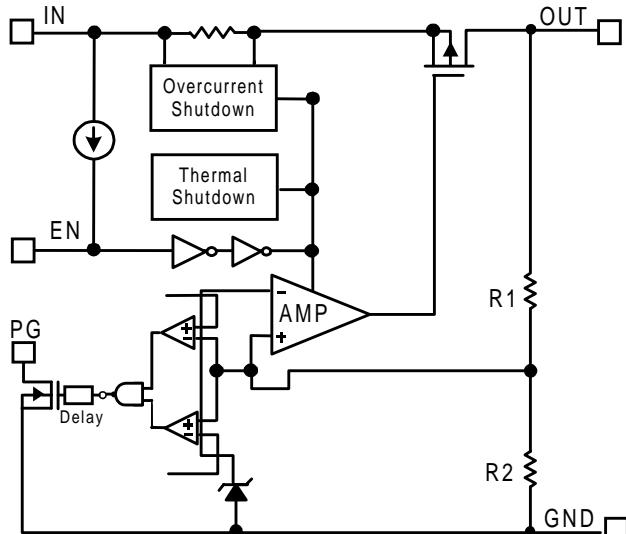
■ Features

- Very Low Dropout Voltage
- Guaranteed 150mA Output
- Accurate to within 3%
- 30 μ A Quiescent Current
- Over-Temperature Shutdown
- Current Limiting
- Short Circuit Current Fold-back
- Power Good Output Function
- Power-Saving Shutdown Mode
- Space-Saving SOT-25 (SOT-23-5)
- Low Temperature Coefficient

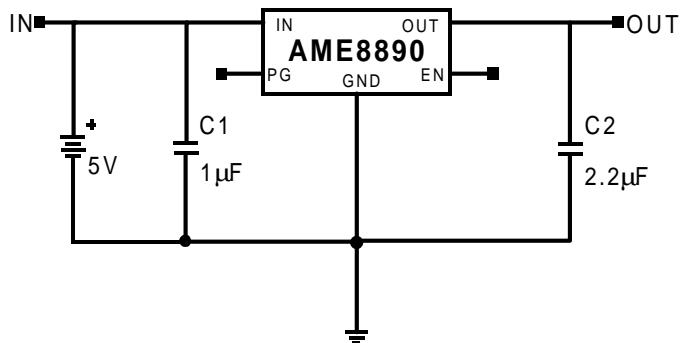
■ Applications

- Instrumentation
- Portable Electronics
- Wireless Devices
- Cordless Phones
- PC Peripherals
- Battery Powered Widgets
- Electronic Scales

■ Functional Block Diagram



■ Typical Application





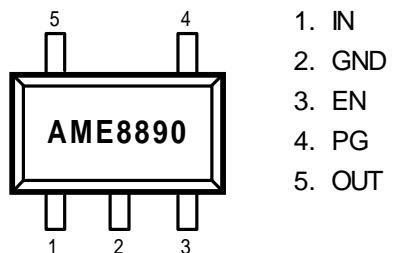
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150mA CMOS LDO

■ Pin Configuration

SOT-25 Top View



1. IN
2. GND
3. EN
4. PG
5. OUT

■ Ordering Information

Part Number	Marking	Output Voltage	Package	Operating Temp. Range
AME8890TEEV	ATBww	1.2V	SOT-25	-40°C to +85°C

ww: represents the date code

Please consult AME sales office or authorized Rep./Distributor for other package type availability.

■ Absolute Maximum Ratings

Parameter	Maximum	Unit
Input Voltage	7	V
Output Current	$P_D / (V_{IN} - V_O)$	mA
Output Voltage	GND - 0.3 to $V_{IN} + 0.3$	V
ESD Classification	B	

Caution: Stress above the listed absolute maximum rating may cause permanent damage to the device.

■ Recommended Operating Conditions

Parameter	Rating	Unit
Ambient Temperature Range	-40 to +85	°C
Junction Temperature	-40 to +125	°C

■ Thermal Information

Parameter	Maximum	Unit
Thermal Resistance (θ_{ja})	260	°C / W
Internal Power Dissipation (P_D) ($\Delta T = 100^\circ\text{C}$)	380	mW
Maximum Junction Temperature	150	°C
Maximum Lead Temperature (10 Sec)	300	°C



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■ Electrical Specifications

$V_{IN} = 2.7V$, $V_{EN} = V_{IN}$, $I_{OUT}=100\mu A$, $TA = 25^\circ C$ unless otherwise noted

Parameter	Symbol	Test Condition		Min	Typ	Max	Units
Input Voltage	V_{IN}			2.7		6	V
Output Voltage Accuracy	V_O	$I_O=0.1mA$		-3		3	%
Dropout Voltage	$V_{DROPOUT}$	$I_O=150mA$ $V_{OUT}=V_O-2.0\%$	1.0V< $V_{O(NOM)}$ <=2.0V			1300	mV
			2.0V< $V_{O(NOM)}$ <=2.8V			N/A	
			2.8V< $V_{O(NOM)}$			N/A	
Current Limit	I_{LIM}	$V_O<0.1V$		150	350		mA
Quiescent Current	I_Q	$V_{IN}=6V$, $I_O=0mA$, $V_O=V_O(\text{nom})$			30	50	μA
Ground Pin Current	I_{GND}	$V_{IN}=6V$, $I_O=1mA$ to $150mA$			35		μA
Line Regulation	REG_{LINE}	$I_O=100\mu A$ $V_{IN}=2.7V$ to $6V$	$1.0 \leq V_O \leq 2.0V$	-0.3		0.3	%
Load Regulation	REG_{LOAD}	$I_O=100\mu A$ to $150mA$		-4	1	4	%
Over Temperature Shutdown	OTS				150		$^\circ C$
Over Temperature Hysteresis	OTH				30		$^\circ C$
V_O Temperature Coefficient	TC				30		$\text{ppm}/^\circ C$
Power Supply Rejection	PSRR	$I_O=100mA$ $C_O=2.2\mu F$	f=1kHz		50		
			f=10kHz		20		dB
			f=100kHz		15		
Output Voltage Noise	eN	$f=10Hz$ to $100kHz$ $I_O=10mA$	$C_O=2.2\mu F$		30		μV_{rms}
EN Input Threshold	V_{EH}			1.6		V_{IN}	V
	V_{EL}			0		0.4	V
EN Input Bias Current	I_{EH}	$V_{EN}=V_{IN}$			0.1		μA
	I_{EL}	$V_{EN}=0V$			0.1		μA
Shutdown Supply Current	I_{SD}	$V_{IN}=5V$, $V_O=0V$, $V_{EN}=0V$			0.5	1	μA
Shutdown Output Voltage	$V_{O,SD}$	Output Loading <= 1200 ohm, $V=0V$		0		0.4	V
Output Under Voltage	V_{UV}	PG ON @ % of V_{OUT}				95	% $V_{O(NOM)}$
PG Leakage Current	I_{LC}	$V_{PG}=6V$, PG is off			0.1		μA
PG Voltage Low	V_{OL}	$I_{SINK}=0.1mA$				0.1	V
PG Delay	T_{PGD}	See Timing Diagram on page 6		1.5		5	ms

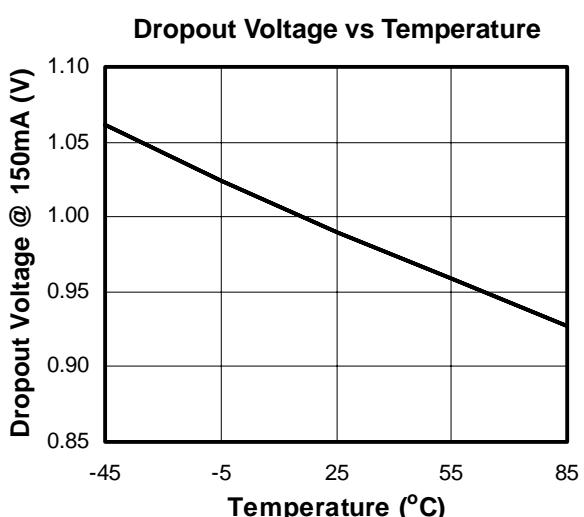
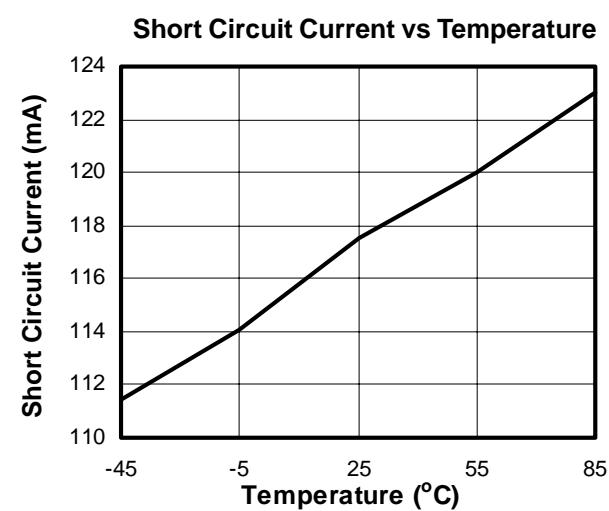
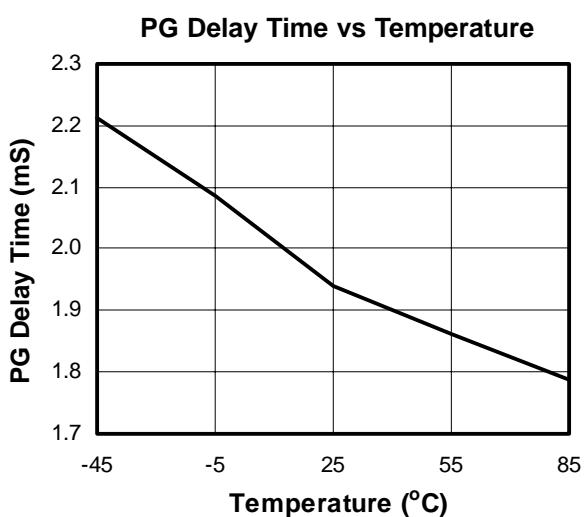
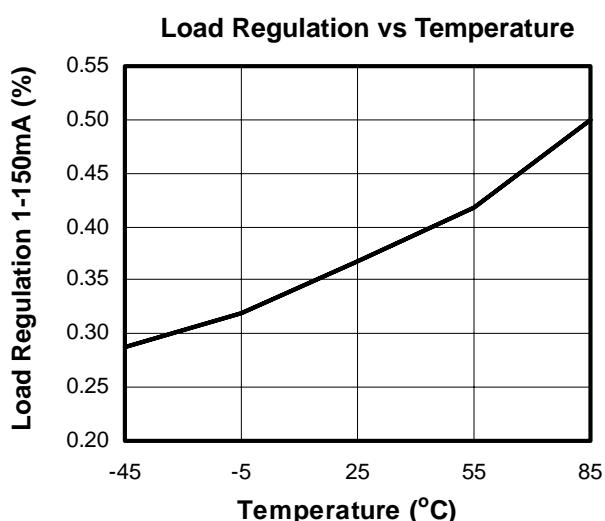
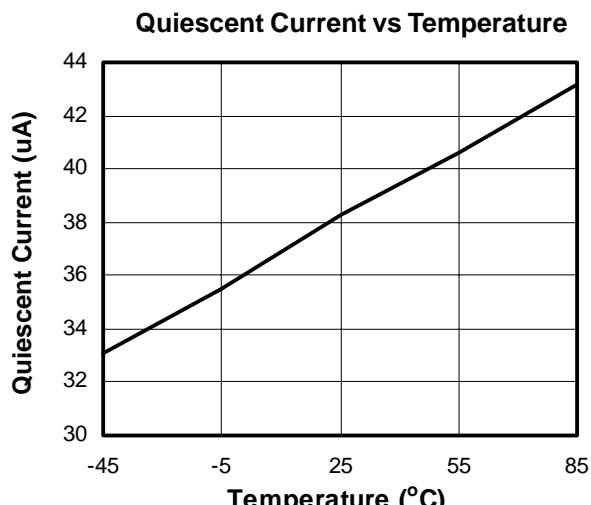
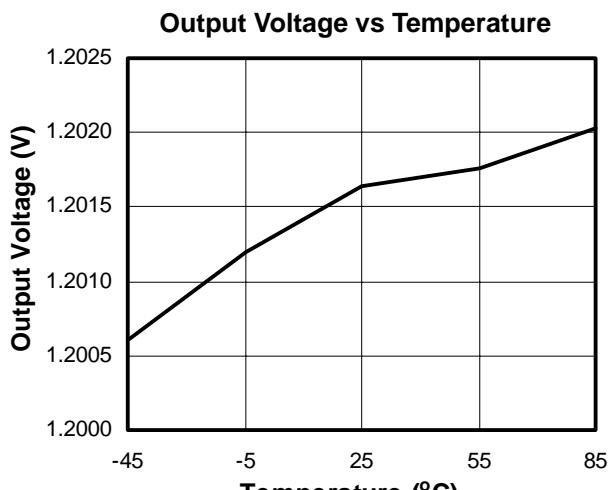
Note1: $V_{IN(min)}=V_{OUT}+V_{DROPOUT}$



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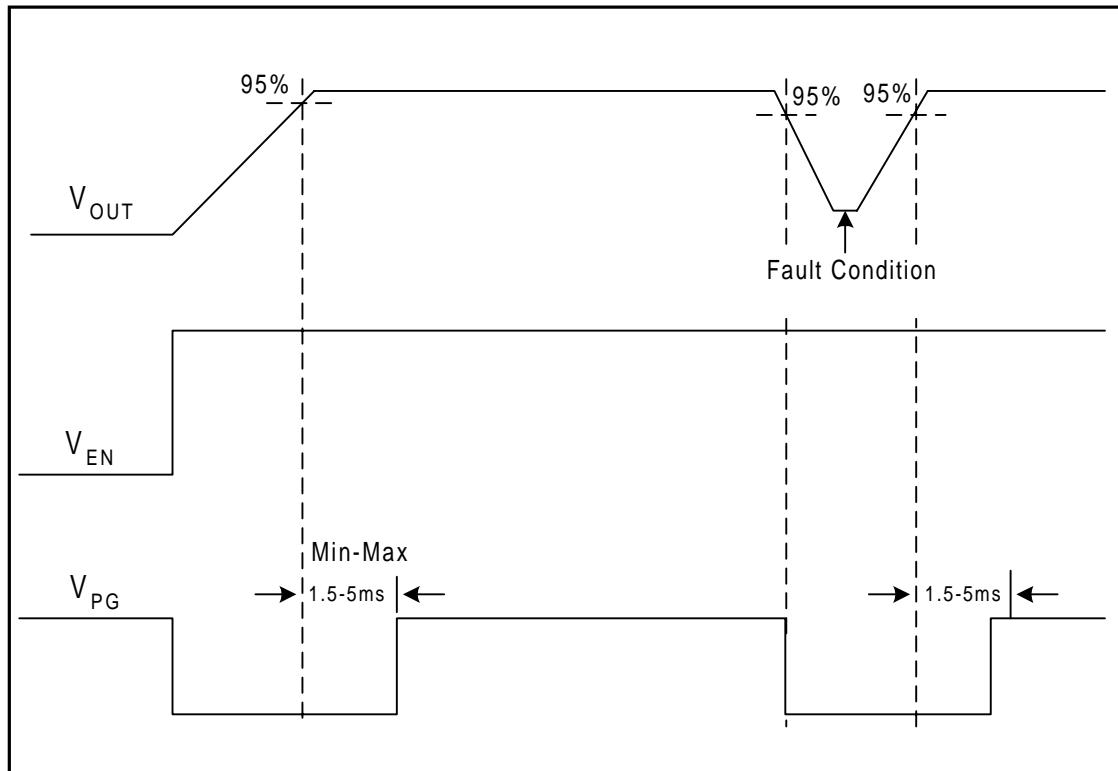
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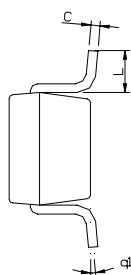
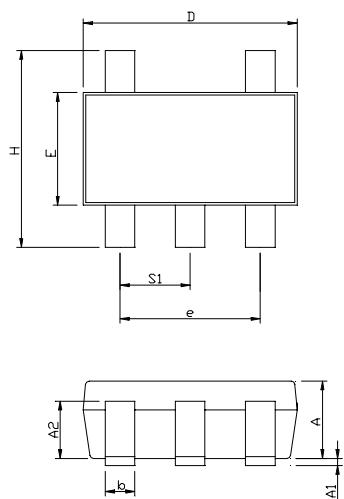


■ Timing Diagram



■ Package Dimension

SOT-25



SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.00	1.45	0.0394	0.0571
A₁	0.00	0.15	0.0000	0.0591
A2	0.70	1.25	0.0276	0.0492
b	0.35	0.55	0.0138	0.0217
C	0.08	0.25	0.0031	0.0098
D	2.70	3.10	0.1063	0.1220
E	1.40	1.80	0.0551	0.0709
e	1.90 BSC		0.07480 BSC	
H	2.60	3.00	0.1024	0.1181
L	0.30	-	0.0118	-
θ1	0°	10°	0°	10°
s₁	0.85	1.05	0.0335	0.0413



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